Diode Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Glass

**Overall Length:** 

0.260 inches

# **Terminal Length:**

1.000 inches

# **Overall Diameter:**

0.250 inches

### **Mounting Method:**

Terminal

### **Features Provided:**

Hermetically sealed case

## **Criticality Code Justification:**

Zzzy

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

400.0 reverse voltage, peak

## **Current Rating Per Characteristic:**

5.00 amperes forward current, average absolute

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

## **Special Features:**

Item must comply with requirements of defense supply center columbus production standard no. Lo4338; junction pattern arrangement: pn

## **Terminal Type And Quantity:**

2 uninsulated wire lead

## **Reference Number Differentiating Characteristics:**

Breference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing and testing specifications available at the dla icp.

## Shelf Life:

N/a

### Unit Of Measure:

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### **Demilitarization:**

No

## Fiig:

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